

SAM™ Data Sheet SAM-1064-60-4ps-x, λ = 1040 nm

| Laser wavelength | $\lambda = 1064 \text{ nm}$ |
|---|---|
| High reflection band | λ = 1010 1110 nm |
| Absorbance | A ₀ = 60 % |
| Modulation depth | ∆R = 36 % |
| Non-saturable loss | A _{ns} = 24 % |
| Saturation fluence | Φ_{sat} = 30 µJ/cm ² |
| Relaxation time constant | τ ~ 4 ps |
| Damage threshold | Φ = 600 µJ/cm ² |
| Chip area | 4.0 mm x 4.0 mm; other dimensions on request |
| Chip thickness | 450 μm |
| Protection | the SAM is protected with a dielectric front layer |
| Mounting option x denotes the type of mounting as follows: x = 0 unmounted x = 12.7 m where a need related Cu culinder with 12.7 mm C | |
| x = 12.7 g | glued on a gold plated Cu-cylinder with 12.7 mm \oslash |

x = 12.7 gglued on a gold plated Cu-cylinder with 12.7 mm \varnothing x = 25.4 gglued on a gold plated Cu-cylinder with 25.4 mm \varnothing x = 12.7 ssoldered on a gold plated Cu-cylinder with 12.7 mm \varnothing x = 25.4 ssoldered on a gold plated Cu-cylinder with 25.4 mm \varnothing x = FCmounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance

